

• General Description

It combines trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. It is suitable for automotive application.

• Features

- AEC-Q101 Qualified
- Low $R_{DS(ON)}$ to minimize conductive loss
- High GOX reliability
- Low Thermal resistance

• Application

- BLDC Motor driver
- DC-DC
- Load Switch

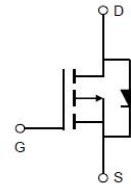
• Ordering Information:

Part NO.	ZMA120P04D
Marking	ZM120P04
Packing Information	REEL TAPE
Basic ordering unit (pcs)	2500

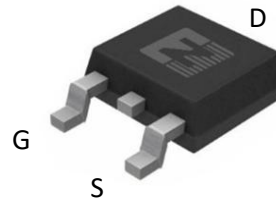
• Absolute Maximum Ratings ($T_C=25^{\circ}C$)

Parameter	Symbol	Conditions	Value	Unit
Drain-Source Voltage	V_{DS}		-40	V
Gate-Source Voltage ^①	V_{GS}		±20	V
Continuous Drain Current	I_D	$T_C=25^{\circ}C$	-45	A
	I_D	$T_C=75^{\circ}C$	-40	A
	I_D	$T_C=100^{\circ}C$	-34	A
Pulsed Drain Current	I_{DM}	Pulsed; $t_p \leq 10 \mu s$; $T_{mb} = 25^{\circ}C$;	-180	A
Total Power Dissipation	P_D	$T_C=25^{\circ}C$	75	W
Total Power Dissipation	P_D	$T_A=25^{\circ}C$	2.4	W
Operating Junction Temperature	T_J		-55 to +175	$^{\circ}C$
Storage Temperature	T_{STG}		-55 to +175	$^{\circ}C$
Single Pulse Avalanche Energy	E_{AS}	L=0.1mH, $V_{GS}=-10V$, $R_g=25\Omega$,	80	mJ
		L=0.5mH, $V_{GS}=-10V$, $R_g=25\Omega$,	168	mJ
ESD Level (HBM)	CLASS 2			

• Product Summary



$V_{DS} = -40V$
 $R_{DS(ON)} = 12m\Omega$
 $I_D = -45A$



TO-252



•Thermal resistance

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal resistance, junction - case	R_{thJC}		-	2	$^{\circ}C/W$
Thermal resistance, junction-ambient ^②	R_{thJA}		-	62	$^{\circ}C/W$
Soldering temperature(total time<10s)	T_{sold}		-	260	$^{\circ}C$

•Electronic Characteristics

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-40			V
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=-250\mu A$	-1.3	-1.8	-2.5	V
Drain-Source Leakage Current	I_{DSS}	$V_{GS}=0V, V_{DS}=-40V$			1.0	μA
Gate- Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			100	nA
Static Drain-source On Resistance	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-15A$		12	16	m Ω
		$V_{GS}=-4.5V, I_D=-10A$		17	21	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=-5V, I_{SD}=-10A$		18		S
Diode Forward Voltage	V_{FSD}	$V_{GS}=0V, I_{SD}=-15A$			1.3	V

•Dynamic characteristics

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input capacitance	C_{iss}	$f=1MHz, V_{DS}=-25V$	-	3430	-	pF
Output capacitance	C_{oss}		-	262	-	
Reverse transfer capacitance	C_{rss}		-	206	-	
Gate Resistance	R_g	$f=1MHz$	-	9		Ω
Total gate charge	Q_g	$V_{DD}=-15V, I_D=-20A, V_{GS}=-10V$	-	56	-	nC
	$Q_g(-4.5v)$		-	25	-	
Gate - Source charge	Q_{gs}		-	7.6	-	
Gate - Drain charge	Q_{gd}		-	10.8	-	
Turn-ON Delay time	$t_{D(on)}$		-	12	-	
Turn-ON Rise time	t_r	$V_{GS}=-10V, V_{DS}=-15V, R_G=3.3\Omega, I_D=-20A$	-	19	-	ns
Turn-Off Delay time	$t_{D(off)}$		-	94	-	ns
Turn-Off Fall time	t_f		-	35	-	ns
Reverse Recovery Time	t_{RR}		$V_{DD}=-20V, di_S/dt=100A/\mu s, I_S=-20A$	-	102	-
Reverse Recovery Charge	Q_{RR}		-	385	-	nC

Fig.1 Gate-Charge Characteristics

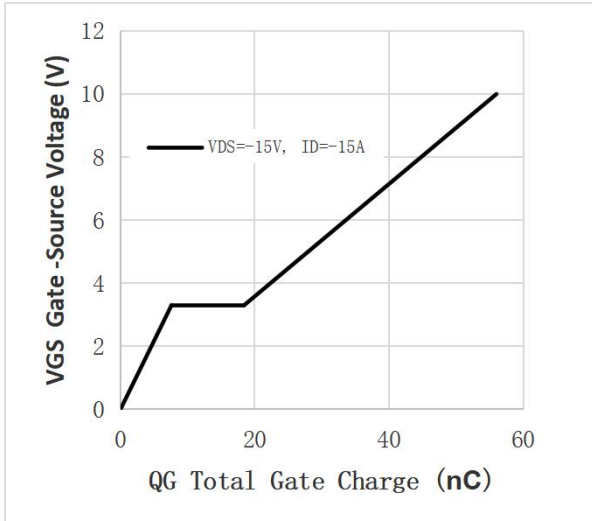


Fig.2 Capacitance Characteristics

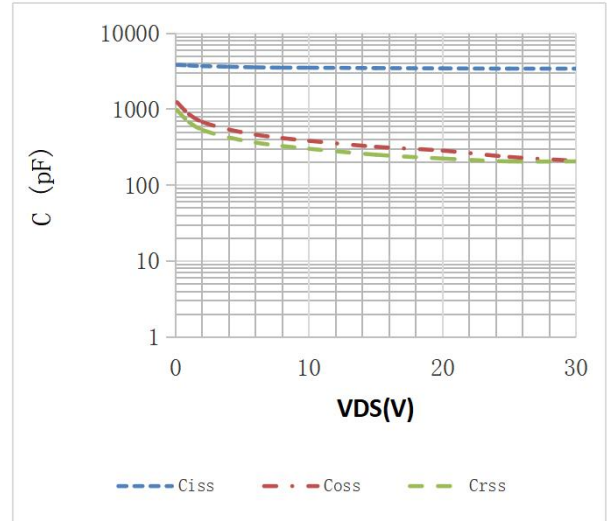


Fig.3 Power Dissipation

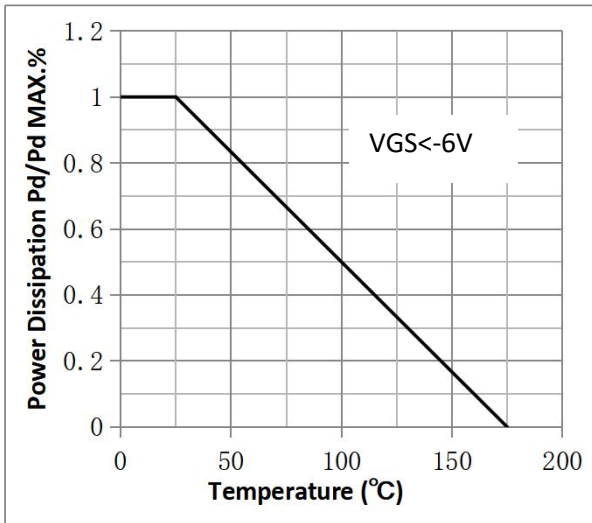


Fig.4 Typical output Characteristics

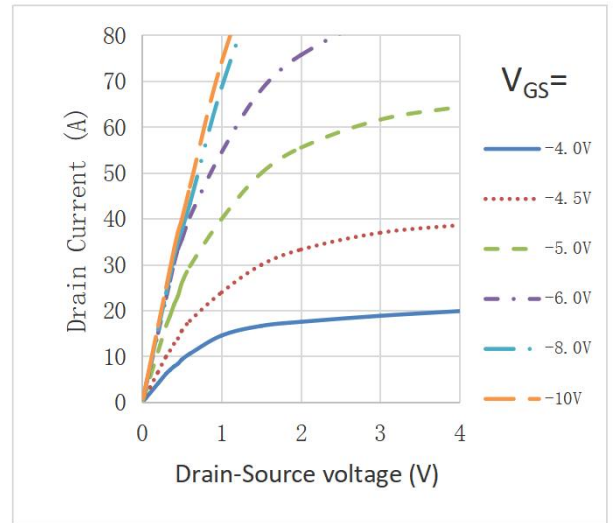


Fig.5 Threshold Voltage V.S Junction Temperature

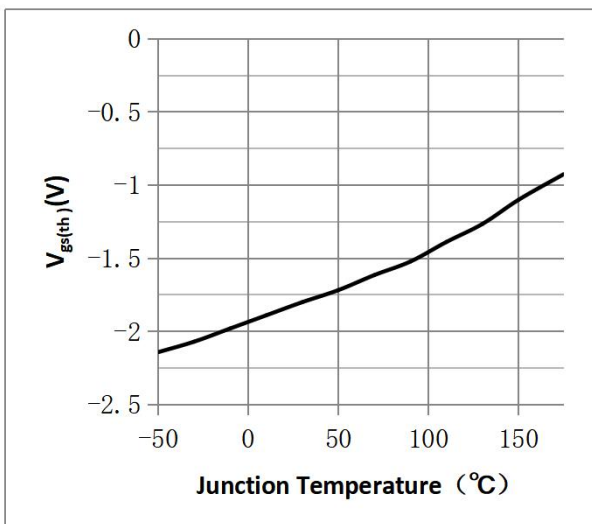


Fig.6 Resistance V.S Drain Current

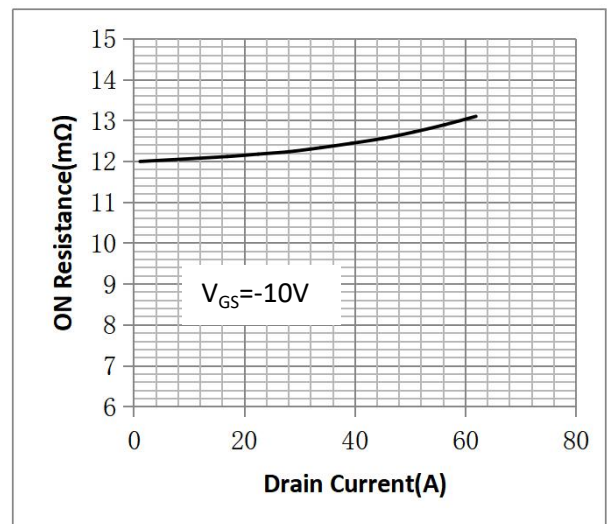


Fig.7 On-Resistance VS Gate Source Voltage

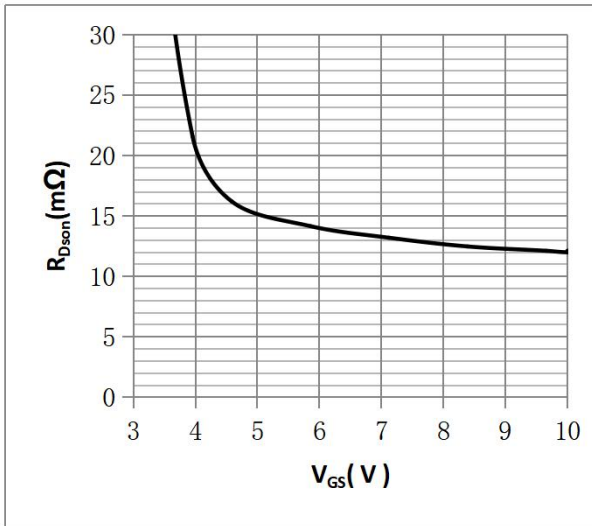


Fig.8 On-Resistance V.S Junction Temperature

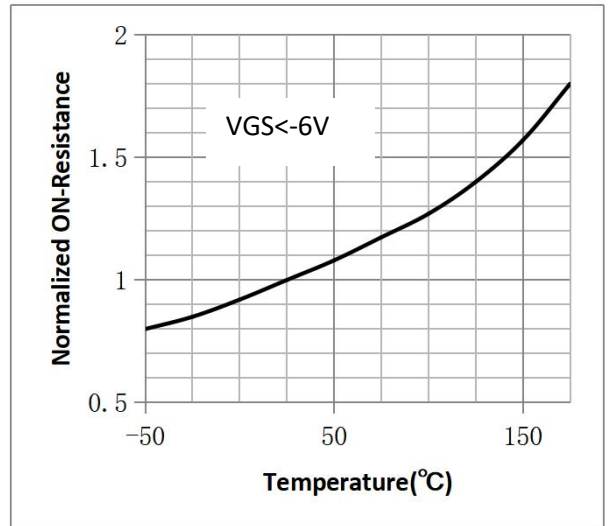


Figure 9. Diode Forward Voltage vs. Current

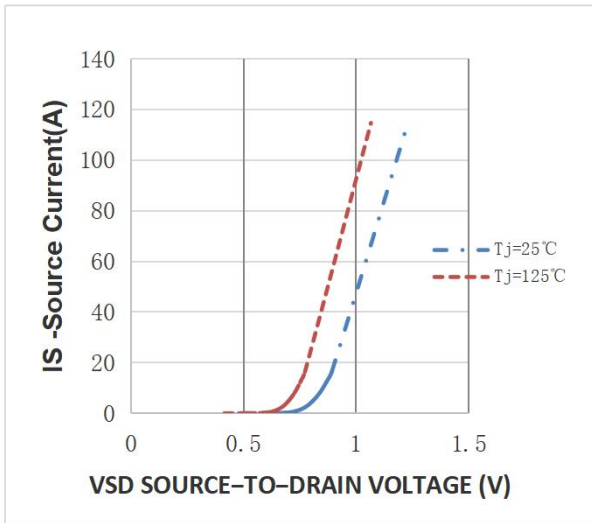


Figure 10. Transfer Characteristics

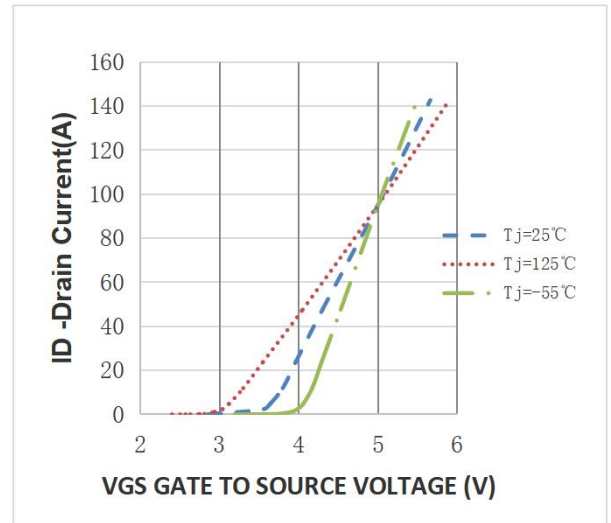


Fig.11 Safe Operating Area

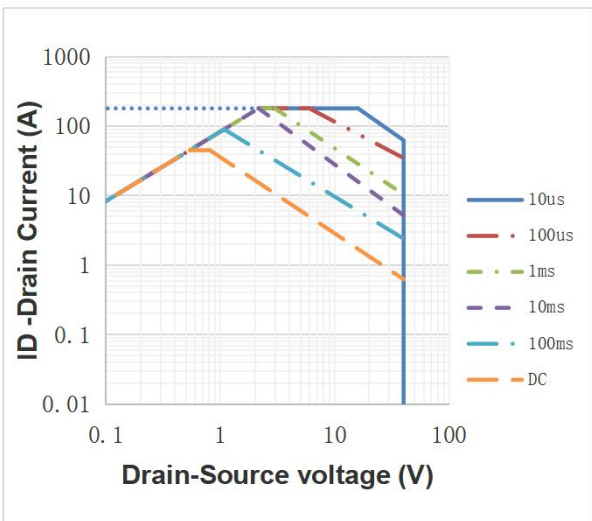
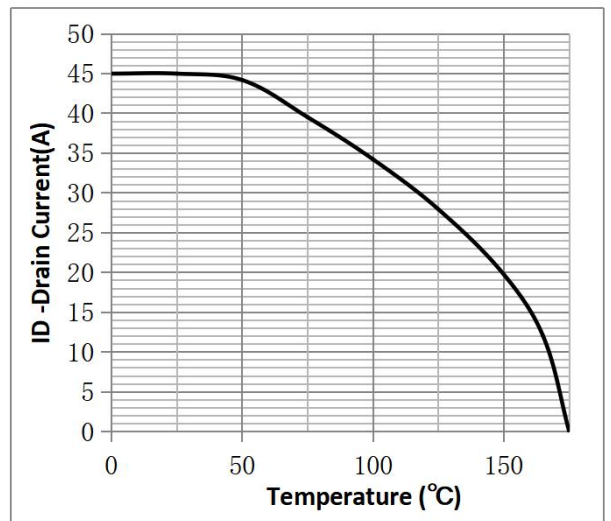
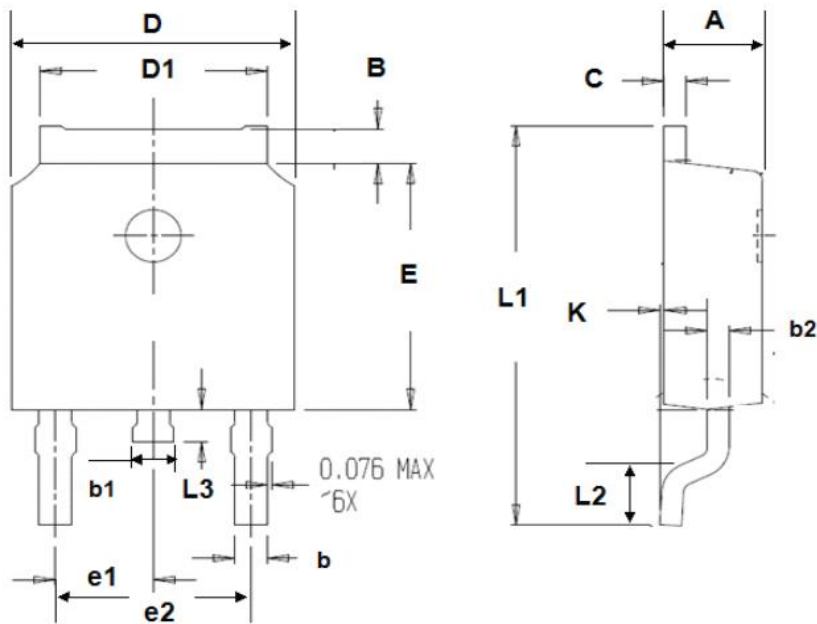


Fig.12 ID vs. Case Temperature^③



•TO-252 Package Outline

SYMBOL	min	max	SYMBOL	min	max
A	2.10	2.50	B	0.85	1.25
b	0.50	0.90	b1	0.50	0.90
b2	0.45	0.70	C	0.45	0.70
D	6.30	6.75	D1	5.10	5.50
E	5.30	6.30	e1	2.24	2.35
L1	9.20	10.60	e2	4.43	4.75
L2	0.90	1.75	L3	0.60	1.10
K	0.00	0.23			



Note:

- ① Pulse : $V_{GS}=+20V/-20V$, Duty cycle=50%, $T_j=175^{\circ}C$, $t=1000$ hours; For DC , the following test conditions can be passed: $V_{GS}=-20V/+10V$, $T_j=175^{\circ}C$, $t=1000$ hours;
- ② Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate;
- ③ Practically the current will be limited by PCB, thermal design and operating temperature. $V_{GS}=-10V$.

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Revision History

Version	Date	Change
A	2021.2.25	
B	2022.6.7	1.Add Reach,HF figure,2.ID modify
C	2022.10.20	1.Add It is suitable for automotive application. 2.Add total time<10s 3.ID curve modified
D	2023.12.19	Correct SOA

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